# AC6381A Datasheet

# Zhuhai Jieli Technology Co.,LTD

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## **AC6381A Features**

#### High performance 32-bit RISC CPU

- 32-bit DSP supports hardware Float Point Unit(FPU)
- Up to 160MHz programmable processor
- 64 Vectored interrupts
- 8 Levels interrupt priority

#### Flexible I/O

- 24 GPIO pins
- All GPIO pins can be programmable as input or output individually
- All GPIO pins are internal pull-up/pull-down selectable individually
- CMOS/TTL level schmitt triggered input
- External wake up/interrupt on all GPIOs

#### **Peripheral Feature**

- One Full Speed USB OTG controller
- Six Multi-function 32-bit timers, support capture and PWM mode
- Three full-duplex basic UART, support DMA mode
- Two SPI interface supports host and device mode
- One hardware IIC interface supports host and device mode
- Two Built-in low power Cap Sense Keys
- Built-in Cap Sense Key controller
- 10-bit ADC for analog sampling
- Power-on reset

#### **Bluetooth Feature**

Compliant with Bluetooth

- V5.3+BR+EDR+BLE specification
- Meet class1 class2 and class3 transmitting power requirement
- Support GFSK and π/4 DQPSK all packet types
- Provides maximum +8dbm@BDR,+6dbm@EDR transmitting power
- Receiver with -94dBm@EDR sensitivity
- Fast AGC for enhanced dynamic range
- Supports

  a2dp\avctp\avdtp\avrcp\hfp\spp\smp\att\gap
  gatt\rfcomm\sdp\l2cap profile
- a2dp 1.3\avctp 1.4\avdtp 1.3\avrcp 1.5\ hfp 1.5 \spp 1.0\rfcomm 1.2\pnp 1.3\ hid 1.0\sdp core4.2\l2cap core 4.2

#### **Power Supply**

- Low voltage LDO for internal digital and analog circuit supply
- 2uA current consumption in the soft-off mode
- Built-in LDO for the core, I/O, Bluetooth and flash
- **VBAT** is 1.8V to 5.5V **VDDIO** is 1.8V to 3.4V

#### **Packages**

**QFN32(4x4mm)** 

### **Temperature**

- Operating temperature: -40°C to +85°C
- Storage temperature: -65°C to +150°C

# 1. Pin Definition

# 1.1 Pin Assignment

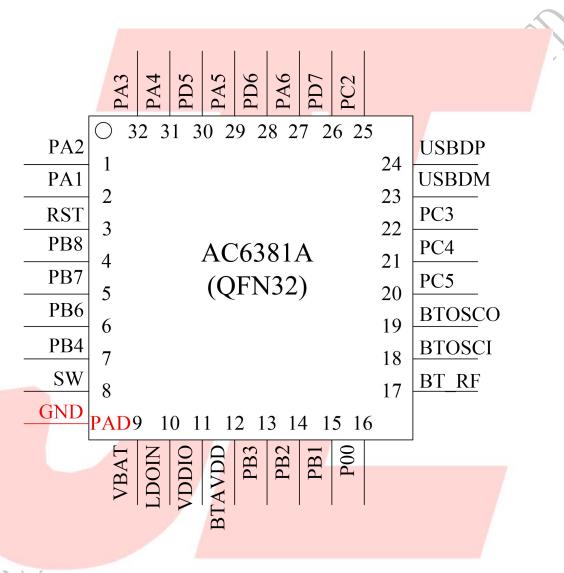


Figure 1-1 AC6381A\_QFN32 Package Diagram

# 1.2 Pin Description

Table 1-1 AC6381A\_QFN32 Pin Description

PIN NO.	Name	I/O Type	Function	Other Function
1	PA2	I/O	GPIO	CAP3: Timer3 Capture; UART1_RXC: Uart1 Data In(C);
2	PA1	I/O	GPIO	SPI1_DIC: SPI1 Data In(C); PWM0: Timer0 PWM Output; UART1_TXC: Uart1 Data Out(C);
3	RST	I	GPIO	RESET:Hight Active;
4	PB8	I/O	GPIO (High Voltage)	UART0_RXB: Uart0 Data In(B); CAP4: Timer4 Capture;
5	PB7	I/O	GPIO	SPI1_DOA: SPI1 Data Out(A); Q-decoder1; TOUCH1:Touch Input Channel 6 ADC8: ADC Channel 8; UART0_TXB: Uart0 Data Out(B);
6	PB6	I/O	GPIO	SPI1_CLKA: SPI1 Clock(A); Q-decoder0; ADC9: ADC Channel 9; TOUCH7:Touch Input Channel 7; UART1_RXA: Uart1 Data In(A); PWM2: Timer2 PWM Output;
7	PB4	I/O	GPIO	CLKOUT0; LVD:Low Voltage Detect; SPI1_DIA: SPI1 Data In(A); ADC12: ADC Channel 12; TOUCH6:Touch Input Channel 6; UAR1_TXA: Uart1 Data Out(A); TMR2: Timer2 Clock In;
8	SW	P	DC-DC Switch Pin	-
9	VBAT	P	LDO Power	-
10	LDOIN	P	Charge Power 5V	PWM3: Timer3 PWM Output;  UART0_TXC: Uart0 Data Out(C);  UART0_RXC: Uart0 Data In(C);
11	VDDIO	P	IO Power 3.3V	-

12	BTAVDD	P	Core Power	_
12	DIAVDD	1	1.3V	
				SPI2_DIC: SPI2 Data In(C);
13	PB3	I/O	GPIO	UART1_TXB: Uart1 Data Out(B);
13	1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1	1/0	GHO	UART1_RXB: Uart1 Data In(B);
				TMR4: Timer4 Clock In;
				SPI2_DOC: SPI2 Data Out(C);
				ADC7: ADC Channel 7;
14	PB2	I/O	GPIO	UART2_RXC: Uart2 Data In(C);
				CAP5: Timer5 Capture;
				LP_TH1: Low Power Touch Channel 1;
				Long Press Reset;
1.5	DD 1	1/0	GPIO	UART2_TXC: Uart2 Data Out(C);
15	PB1	I/O	(pull up)	ADC6: ADC Channel 6;
				LP_TH0: Low Power Touch Channel 0;
4.6	700	7/0	GPIO	
16	P00	I/O	(High Voltage)	
17	BT_RF	-	RF Antenna	- /
18	BTOSCI	I	BTOSCI	-
19	BTOSCO	0	BTOSCO	- /
				SPI1 DOB: SPI1 Data Out(B);
				IIC SDA B: IIC SDA(B);
20	PC5	I/O	GPIO	ADC5: ADC Channel 5;
			0	UART2 RXD: Uart2 Data In(D);
				SPI1_CLKB: SPI1 Clock(B);
			7	IIC_SCL_B: IIC SCL(B);
21	PC4	I/O	GPIO	ADC4: ADC Channel 4;
21	104	1/0	GHO	UART2_TXD: Uart2 Data Out(D);
			7.7	PWM4: Timer4 PWM Output;
				SPI1 DIB: SPI1 Data In(B);
				IIC_SDA_C: IIC SDA(C);
				ADC3: ADC Channel 3;
22	PC3	I/O	GPIO	TOUCH5:Touch Input Channel 5;
	1			
	>			UART0_RXD: Uart0 Data In(D); TMR3: Timer3 Clock In;
K Y	<u> </u>			
			CDIO	SPI2_DOB: SPI2 Data Out(B);
23	USBDM	I/O	GPIO	IIC_SDA_A: IIC SDA(A);
			(pull down)	ADC11: ADC Channel 11;
				UART1_RXD: Uart1 Data In(D);
			CDIC	SPI2_CLKB: SPI2 Clock(B);
24	USBDP	I/O	GPIO	IIC_SCL_A: IIC SCL(A);
			(pull down)	ADC10: ADC Channel 10;
				UART1_TXD: Uart1 Data Out(D);
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			ı	
				SPI2_DIB: SPI2 Data In(B);
				IIC_SCL_C: IIC SCL(C);
25	PC2	I/O	GPIO	TOUCH4:Touch Input Channel 4;
				UART0_TXD: Uart0 Data Out(D);
				TMR1: Timer1 Clock In;
26	PD7	I/O	GPIO	UART2_RXB: Uart2 Data In(B);
20	PD/	1/0	GPIO	TMR5: Timer5 Clock In;
				UART1_RTS;
				SPI2_DOA: SPI2 Data Out(A);
				IIC_SDA_D: IIC SDA(D);
27	PA6	I/O	GPIO	ADC2: ADC Channel 2;
				TOUCH3:Touch Input Channel 3;
				UART0_RXA: Uart0 Data In(A);
				CAP0: Timer0 Capture;
20	PD (	7/0	anta.	UART2_TXB: Uart2 Data Out(B);
28	PD6	I/O	GPIO	TMR0: Timer0 Clock In;
			A	UART1_CTS;
			4	SPI2_CLKA: SPI2 Clock(A);
				IIC_SCL_D: IIC SCL(D);
29	PA5	I/O	GPIO	ADC1: ADC Channel 1;
				TOUCH2:Touch Input Channel 2;
				UART0_TXA: Uart0 Data Out(A);
			A	PWM5: Timer5 PWM Output;
			GPIO	
30	PD5	I/O	(Output 0)	
				SPI2_DIA: SPI2 Data In(A);
31	PA4	I/O	GPIO	UART2_RXA: Uart2 Data In(A);
			(High Voltage)	CAP2: Timer2 Capture;
				SPI1_DOC: SPI1 Data Out(C);
V				ADC0: ADC Channel 0;
32	PA3	I/O	GPIO	TOUCH0:Touch Input Channel 0;
				UART2_TXA: Uart2 Data Out(A);
				PWM1: Timer1 PWM Output;
	PAD	P	GND	-
	-7-	<u> </u>		

# 2. Electrical Characteristics

# 2.1 Absolute Maximum Ratings

Table 2-1

Symbol	Parameter	Min	Max	Unit
Topt	Operating temperature	-40	+85	°C
Tstg	Storage temperature	-65	+150	°C
VBAT	Supply Voltage	-0.3	5.5	V
LDOIN	Charge Input Voltage	-0.3	6	V
VDDIO	3.3V IO Input Voltage	-0.3	3.6	V

Note: The chip can be damaged by any stress in excess of the absolute maximum ratings listed below

# 2.2 Recommended Operating Conditions

Table 2-2

Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
VBAT	Voltage Input	1.8	3.7	5.5	V	_
LDOIN	Voltage Input	4.5	5.0	5.5	V	_
Normal mod	e					
VDDIO	Voltage output	-	3.0	-	V	VBAT= 4.2V, 10mA loading
VIDIO	Loading current	-	-/	100	mA	VDDIO=3V@VBAT = 4.2V
BTAVDD	Voltage output	-	1.25	-	V	VDDIO=3V,10mA loading
BIAVDD	Loading current	-	7-1	60	mA	BTAVDD=1.25V@VDDIO = 3V
LP mode		,				
VDDIO	Loading current	_	-	5	mA	VDDIO=3V@VBAT = 4.2V

# 2.3 Battery Charge

Table 2-3

Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
LDOIN	Charge Input Voltage	4.5	5	5.5	V	-
V	Charga Valtaga	4.15	4.2	4.25	V	LDOIN>4.5V
$ m V_{Charge}$	Charge Voltage	4.30	4.35	4.40	V	LDOIN-4.3V

$I_{\mathrm{Charge}}$	Charge Current	20		200	mA	Charge current at fast charge mode
${ m I}_{ m Trikl}$	Trickle Charge Current	20	45	70	mA	$V_{\mathrm{BAT}} < V_{\mathrm{Trikl}}$

# 2.4 IO Input/Output Electrical Logical Characteristics

Table 2-4

IO input ch	IO input characteristics									
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions				
$V_{\rm IL}$	Low-Level Input Voltage	-0.3	_	0.3* VDDIO	V	VDDIO = 3.0V				
$ m V_{IH}$	High-Level Input Voltage	0.7* VDDIO	-	VDDIO+0.3	V	VDDIO = 3.0V				
IO output o	characteristics			7.7						
V <sub>OL</sub>	Low-Level Output Voltage	-/	-	0.33	V	VDDIO = 3.0V				
V <sub>OH</sub>	High-Level Output Voltage	2.7	-	-	V	VDDIO = 3.0V				

## 2.5 Internal Resistor Characteristics

Table 2-5

Port	Drive Strength	Internal Pull-Up Resistor	Internal Pull-Down Resistor	Comment
PA1-PA8, PB1-PB7, PC1-PC5, PD5-PD7	drive_select[11] 64mA drive_select[10] 26.4mA drive_select[01] 8mA drive_select[00] 2.4mA	10K	10K	PB1 default pull up     USBDM&USBDP     default pull down
PB8,P00	8mA	10K	10K	3. Internal pull-up/pull-down resistance   accuracy ±20%
USBDP	4mA	1.5K	15K	4. PB8,P00 can pull-up
USBDM	4mA	180K	15K	resistance to 5V

## 2.6 BT Characteristics

### 2.6.1 Transmitter

**Basic Data Rate** 

**Table 2-6** 

Paramete	r	Min	Тур	Max	Unit	Test Conditions
RF Transmit P	RF Transmit Power		6	8	dBm	
RF Power Contro	l Range		20		dB	25°C,
20dB Bandw	20dB Bandwidth		950		KHz	Power Supply
	+2MHz		-40		dBm	
Adjacent Channel	-2MHz		-38	7/	dBm	VBAT=3.7V
Transmit Power	+3MHz		-44	7 /	dBm	2441MHZ
	-3MHz		-35		dBm	

### **Enhanced Data Rate**

Table 2-7

Paramete	er	Min	Тур	Max	Unit	Test Conditions
Relative Po	wer		-1	-3	dB	
π/4 DQPSK	DEVM RMS		6		%	
	DEVM 99%		10		%	25°C,
Modulation Accuracy	DEVM Peak	7	15		%	Power Supply
	+2MHz		-40		dBm	VBAT=3.7V
Adjacent Channel	-2MHz		-38		dBm	2441MHz
Transmit Power	+3MHz		-44	7	dBm	
	-3MHz	7/	-35		dBm	

#### 2.6.2 Receiver

## **Basic Data Rate**

**Table 2-8** 

Paramete	Min	Тур	Max	Unit	Test Conditions	
Sensitivit	Sensitivity		-94		dBm	
Co-channel Interferer	Co-channel Interference Rejection				dB	
	+1MHz		+5		dB	25℃,
	-1MHz		+2		dB	Power Supply
Adjacent Channel	+2MHz		+37		dB	VBAT=3.7V
Interference Rejection	-2MHz		+36		dB	2441MHz
	+3MHz		+40		dB	
	-3MHz		+35		dB	

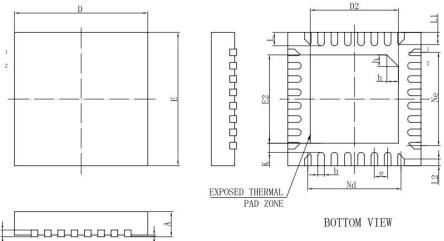
### **Enhanced Data Rate**

Table 2-9

Parameter		Min	Тур	Max	Unit	Test Conditions
Sensitivity			-94		dBm	
Co-channel Interference Rejection			-13		dB	
	+1MHz		+5		dB	25°C,
	-1MHz		+2		dB	Power Supply
Adjacent Channel	+2MHz		+37		dB	VBAT=3.7V
Interference Rejection	-2MHz		+36		dB	2441MHz
	+3MHz		+40		dB	
	-3MHz		+35		dB	

# 3. Package Information

# 3.1 QFN32(4mm\*4mm)

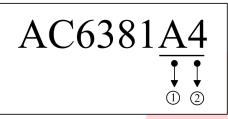


SYMBOL	MILLIMETER				
SIMBOL	MIN	NOM	MAX		
A	0.70	0.75	0.80		
Al	0	0.02	0.05		
b	0.15	0.20	0. 25		
c	0.18	0.20	0.25		
D	3, 90	4.00	4.10		
D2	2.60	2.65	2.70		
e	0. 40BSC				
Nd	2. 80BSC				
E	3.90	4.00	4.10		
E2	2.60	2.65	2, 70		
Ne	2. 80BSC				
K	0.20	570	52		
L	0, 35	0, 40	0.45		
L1	0.30	0, 35	0.40		
L2	0.15	0.20	0. 25		
h	0.30	0, 35	0.40		
L/F载体尺寸 (961)	112*112				



Figure 3-1 AC6381A\_QFN32 Package

# 4. Package Type Specification



- ①Represents different packages
- ②Represents different memory sizes

4: 4Mbit Flash

# 5. Revision History

Date	Revision	Description
2021.05.19	V1.0	Initial Release
2022.07.19	V1.1	Update Bluetooth Feature